

ELEC-313
Lab 7: MOSFET Amplifier Circuits

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1 Objective

2 Equipment

Transistor: 2N7000 Power supply: HP E3631A
Function generator: HP 33120 Multimeter: HP 34401A
Oscilloscope: Agilent 54622D Capacitors: 0.1 μF
Resistors: 100 Ω , 300 Ω , 470 Ω , 1 k Ω (x2) 33 k Ω , 100 k Ω (x2)

3 Schematics

4 Procedure

5 Results

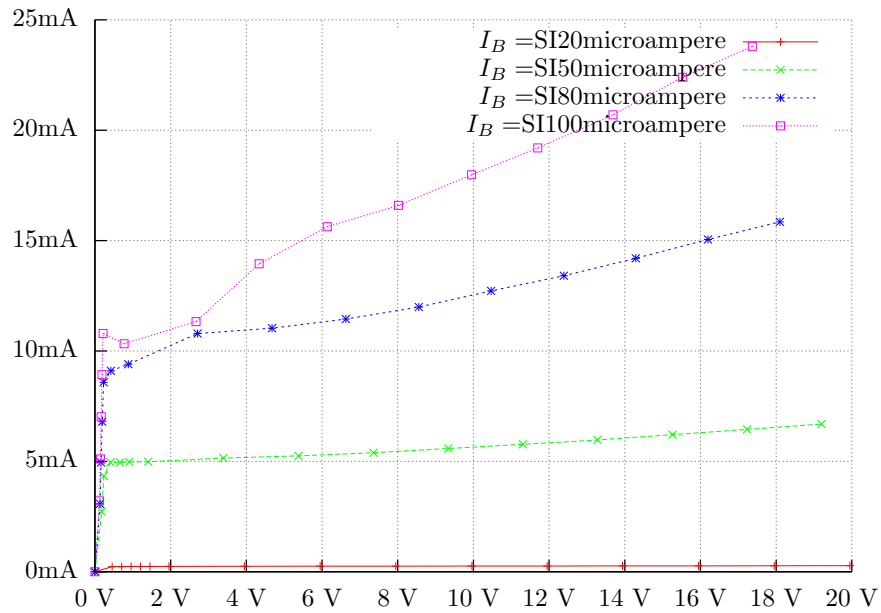


Figure 1: V_{CE} vs. I_C

6 Conclusion

7 Equations

$$V_{o,L} = V_{o,NL} \frac{R_L}{R_o + R_L} \quad (1)$$

$$V_G = \frac{V_{DD} \cdot 33 \text{ k}\Omega}{100 \text{ k}\Omega + 33 \text{ k}\Omega} \quad (2)$$

$$V_S = V_G \cdot \sqrt{\frac{I_D}{K_N}} - V_{TN} \quad (3)$$

$$V_D = V_{DD} - I_D \cdot 1 \text{ k}\Omega \quad (4)$$

$$I_D = \frac{V_S}{R_S} \quad (5)$$

$$A_V = \frac{V_{out}}{V_{in}} = \frac{-g_m \cdot R_D}{1 + g_m \cdot R_S} \quad (6)$$

$$\%_{diff} = \frac{|measured - theoretical|}{theoretical} \times 100\% \quad (7)$$